# SENSITRON

SEMICONDUCTOR

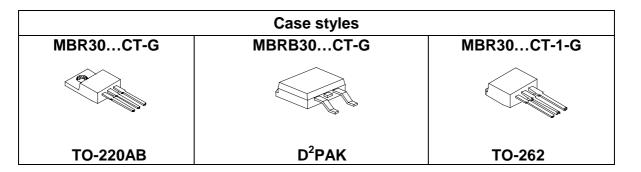
Technical Data Data Sheet 3492, Rev. A **Green Products** 

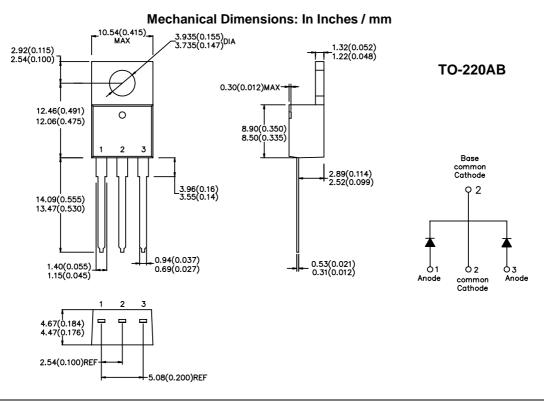
# MBR30...CT-G/MBRB30...CT-G/MBR30...CT-1-G SCHOTTKY RECTIFIER

#### **Applications:**

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection Features:

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



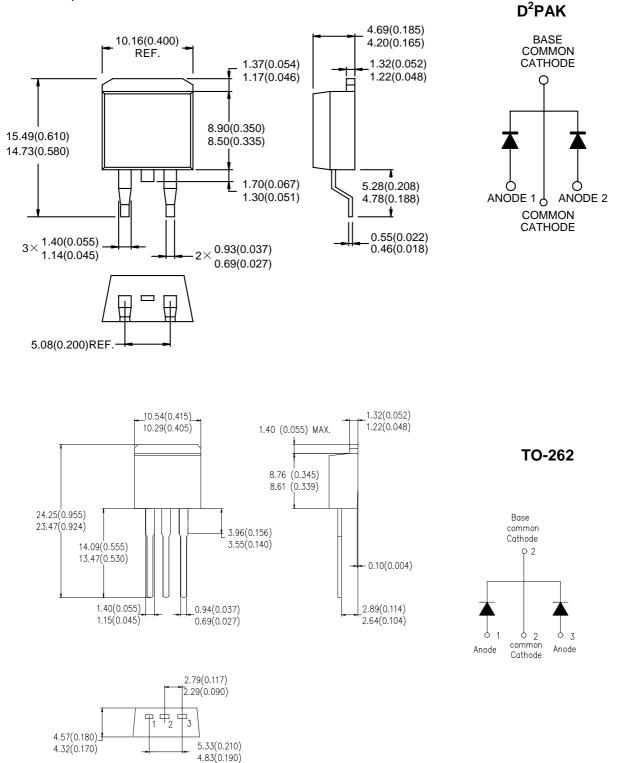


# SENSITRON SEMICONDUCTOR

Technical Data Data Sheet 3492, Rev. A

# MBR3035-G/3045CT-G MBRB3035-G/3045CT-G MBR3035-G/3045CT-1-G

#### Green Products



# SENSITRON SEMICONDUCTOR

## MBR3035-G/3045CT-G MBRB3035-G/3045CT-G MBR3035-G/3045CT-1-G

#### Technical Data Data Sheet 3492, Rev. A Maximum Ratings:

### **Green Products**

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	35	MBR3035CT-G MBRB3035CT-G MBR3035CT-1-G	
			45	MBR3045CT-G MBRB3045CT-G MBR3045CT-1-G	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle $@T_c = 123^{\circ}C$ , rectangular wave form	15(Per leg) 30(Per Device)		A
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse		240	A

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25 °C	0.84	V
	V <sub>F2</sub>	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.57	V
		@ 30A, Pulse, T <sub>J</sub> = 125 °C	0.72	
Max. Reverse Current	I <sub>R1</sub>	$@V_{R} = rated V_{R}$	1.0	mA
(per leg) *		$T_J = 25 \ ^{\circ}C$		
	I <sub>R2</sub>	$@V_R = rated V_R$	40	mA
		T <sub>J</sub> = 100 °C		
Max. Junction Capacitance	CT	@V <sub>R</sub> = 4V, T <sub>C</sub> = 25 °C	500	pF
(per leg)		f <sub>SIG</sub> = 1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

\* Pulse Width < 300µs, Duty Cycle <2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	TJ	-	-55 to +150	°C	
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C	
Maximum Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	1.6	°C/W	
Maximum Thermal Resistance, Case to Heat Sink	R <sub>θJA</sub>	DC operation	50	°C/W	
Approximate Weight	wt	-	2	g	
Mounting Torque	Τ <sub>M</sub>	-	6(Min.) 12(Max.)	Kg-cm	
Case Style	TO-220AB D <sup>2</sup> PAK TO-262				

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## MBR3035-G/3045CT-G MBRB3035-G/3045CT-G MBR3035-G/3045CT-1-G

#### **Green Products**

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